

Cascadable Amplifier
10 to 800 MHz

A67/ SMA67

V2

Features

- AVAILABLE IN SURFACE MOUNT
- HIGH EFFICIENCY: +16 dBm (TYP.)
OUTPUT POWER AT 32 mA (TYP.)
- LOW NOISE FIGURE: <4.0 dB (TYP.)
- WIDE POWER SUPPLY RANGE: +5 TO +15 VOLTS

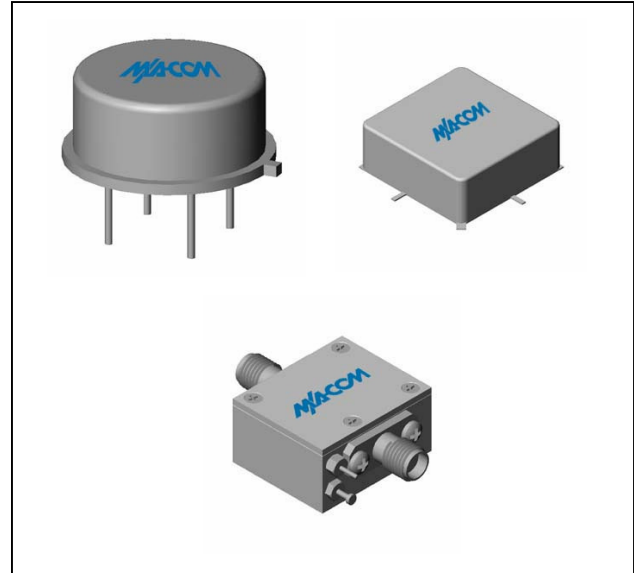
Description

The A67 RF amplifier is a discrete hybrid design, which uses thin film manufacturing processes for accurate performance and high reliability.

This single stage bipolar transistor feedback amplifier design displays impressive performance over a broadband frequency range. Use of an impedance transformer offers the benefit of high dynamic range and high efficiency.

Both TO-8 and Surface Mount packages are hermetically sealed, and MIL-STD-883 environmental screening is available

Product Image



Ordering Information

Part Number	Package
A67	TO-8
SMA67	Surface Mount
CA67	SMA Connectorized

Electrical Specifications: $Z_0 = 50\Omega$, $V_{CC} = +15 V_{DC}$

Parameter	Units	Typical	Guaranteed	
		25°C	0° to 50°C	-54° to +85°C*
Frequency	MHz	10-900	10-800	10-800
Small Signal Gain (min)	dB	14.0	13.0	12.5
Gain Flatness (max)	dB	±0.3	±0.6	±0.7
Reverse Isolation	dB	17		
Noise Figure (max)	dB	4.0	4.3	4.5
Power Output @ 1 dB comp. (min)	dBm	16.0	15.5	15.0
IP3	dBm	+30		
IP2	dBm	+45		
Second Order Harmonic IP	dBm	+50		
VSWR Input / Output (max)		1.8:1 / 2.0:1	1.9:1 / 2.0:1	2.0:1 / 2.2:1
DC Current @ 15 Volts (max)	mA	32	34	35

Absolute Maximum Ratings

Parameter	Absolute Maximum
Storage Temperature	-62°C to +125°C
Case Temperature	+125°C
DC Voltage	+17 V
Continuous Input Power	13 dBm
Short Term Input power (1 minute max.)	50 mW
Peak Power (3 µsec max.)	0.5 W
"S" Series Burn-In Temperature (case)	+125°C

Thermal Data: $V_{CC} = +15 V_{DC}$

Parameter	Rating
Thermal Resistance θ_{jc}	45°C/W
Transistor Power Dissipation P_d	0.269 W
Junction Temperature Rise Above Case T_{jc}	12°C

* Over temperature performance limits for part number CA67, guaranteed from 0°C to +50°C only.

